NSN 5962-01-092-4850

Memory Microcircuit - Page 1 of 1



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Body Length: 1.290 inches **Body Width:** 0.526 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 2.0 watts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and erasable and programmable and w/buffered output and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** P-type metal oxide-semiconductor logic Input Circuit Pattern: 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -20.0 volts power source and 0.5 volts power source **Time Rating Per Chacteristic:** 100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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